	SPEC No.         E L 0 9 3 1 1 5           ISSUE:         Mar. 25, 1997
<u>To;</u>	
· -	:
SPEC	CIFICATIONS
Product Type	256k SRAM
LH5	2256CD-70LL
	( LH525C7D )
Model No	
	ontains <u>15</u> pages including the cover and appendix. tions, please contact us before issuing purchasing order.
	REVIEWED BY: REVIEWED BY: REVIEWED BY: Regineering Dept. 2 Memory IC Engineering Center Tenri Integrated Circuits Group SHARP CORPORATION

#### LH525C7D

- Handle this document carefully for it contains material protected by international copyright law. Any reproduction, full or in part, of this material is prohibited without the express written permission of the company.
- When using the products covered herein, please observe the conditions written herein and the precautions outlined in the following paragraphs. In no event shall the company be liable for any damages resulting from failure to strictly adhere to these conditions and precautions.
  - (1) The products covered herein are designed and manufactured for the following application areas. When using the products covered herein for the equipment listed in Paragraph (2), even for the following application areas, be sure to observe the precautions given in Paragraph (2). Never use the products for the equipment listed in Paragraph (3).
    - Office electronics
      - · Instrumentation and measuring equipment
    - Machine tools
    - · Audiovisual equipment
    - Home appliances
    - Communication equipment other than for trunk lines
  - (2) Those contemplating using the products covered herein for the following equipment which demands high reliability, should first contact a sales representative of the company and then accept responsibility for incorporating into the design fail-sale operation, redundancy, and other appropriate measures for ensuring reliability and safety of the equipment and the overall system.
    - Control and safety devices for airplanes, trains, automobiles, and other transportation equipment
    - Mainframe computers
    - · Traffic control systems
    - · Gas leak detectors and automatic cutoff devices
    - · Rescue and security equipment
    - · Other safety devices and safety equipment, etc.
  - (3) Do not use the products covered herein for the following equipment which demands extremely high performance in terms of functionality, reliability, or accuracy.
    - Aerospace equipment
    - · Communications equipment for trunk lines
    - · Control equipment for the nuclear power industry
    - · Medical equipment related to life support, etc.
  - (4)Please direct all queries and comments regarding the interpretation of the above three Paragraphs to a sales representative of the company.
- Please direct all queries regarding the products covered herein to a sales representative of the company.

### LH525C7D

	Contents	
1.	Description 2	
2.	Pin Configuration ••••••• 2	
3.	Truth Table •••••• 3	
4.	Block Diagram	
5.	Absolute Maximum Ratings 4	
6.	Recommended DC Operating Conditions	
7.	DC Electrical Characteristics ••••••••••••••••••••••••••••••••••••	
8.	AC Electrical Characteristics · · · · · · · · · · · · · · · · · 5	
9.	Data Retention Characteristics ••••••• 6	
10.	Pin Capacitance •••••• 6	
11.	Timing Chart •••••• 7	
12.	Package and Packing Specification	ł

#### LH525C7D

1. Description

The LH52256CD-70LL is a static RAM organized as 32, 768×8 bit with provides low-power standby mode.

It is fabricated using silicon-gate CMOS process technology.

۰.

Features -	•	
OAccess Time		70 ns (Max.)
O0perating current	• • • •	45 mA (Max.)
		$1 0 \text{ mA}$ (Max. trc. twc= $1 \mu \text{s}$ )
OStandby current	• • • •	40 $\mu$ A (Max.)
OData retention current	• • • •	1.0 $\mu$ A (Max. V ccDr = 3 V, Ta = 25°C)
$\bigcirc$ Wide operating voltage range	• • • •	4.5 V to 5.5 V
O0perating temperature	• • • •	0°C to +70°C
OFully static operation		
OThree-state output		
ONot designed or rated as radia	tion hardened	

 $\bigcirc$  2 8 pin SK-DIP( DIP28-P-300 ) plastic package  $\bigcirc$  ON-type bulk silicon

2. Pin Configuration

	· .		
A14 🗖	10	28	
A12 🗖	2	27	🗀 WE
A7 🗖	3	26	A 13
A6 🗖	4	25	
A 5 🖂	5	24	- A 9
A4 🗖	6	23	
A 3 🖂	7	22	
A 2 🗖	8	21	A 10
A1 🗖	9	20	CE
A o	10	19	□ I/O*
I/0 , 🗖	11	18	□ I/07
I/O 2 🗖	12	17	□ I/O 6
I/O 3 🗖	13	16	□ I/O 5
GND 🖂	14	15	□ I/O4
1			1

(1	Cop View)
Pin Name	Function
Ao to A14	Address inputs
CE	Chip enable
WE	Write enable
ŌĒ	Output enable
I /O 1 to I /O s	Data inputs/outputs
Vcc	Power supply
GND	Ground

### LH525C7D

3. Truth Table

CE	WE	ŌĒ	Mode	I /O 1 to I /O s	Supply current
Н	*	*	Standby	High impedance	Standby (Ism)
L	H	L	Read	Data output	Active (I cc)
L	Н -	H	Output disable	High impedance	Active (I <sub>cc</sub> )
L	L	*	Write	Data Input	Active (I cc)

(\*=Don't Care, L=Low, H=High)



#### 5. Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit
Supply voltage (*1) -	Vcc	-0.5 to $+7.0$	V
Input voltage(*1)	VIX	-0.5 (*2) to Vcc+0.5	V
Operating temperature	Topr	0 to + 70	C
Storage temperature	Tstg	-65 to $+150$	C

Note) \*1. The maximum applicable voltage on any pin with respect to GND.
\*2. Undershoot of -3. OV is allowed width of pluse bellow 50ns.

6. Recommended DC Operating Conditions

 $(Ta = 0 \ C \ to + 7 \ 0 \ C)$ 

.....

Parameter	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	Vcc	4.5	5.0	5.5	V
Input voltage	VIH	2.2		Vcc+0.5	V
	VIL	- 0.5 (*3)		0.8	V

Note) \*3. Undershoot of -3.0V is allowed width of pluse below 50ns.

### 7. DC Electrical Characteristics

		$(T_a = 0 \ C \ to + 7 \ C$	)℃,Vcc=	= 4.5 V	to 5.5	V)
Parameter	Symbol	Conditions	Min.	Typ. (*4)	Max.	Unit
Input leakage	ILI	V <sub>IN</sub> =OV to V <sub>CC</sub>	-			
current			-1.0		1.0	μΑ
Output leakage	ILO	$\overline{CE} = V_{1H} \text{ or } \overline{OE} = V_{1H}$				
current		V <sub>1/0</sub> =OV to V <sub>CC</sub>	-1.0		1.0	μA
Operating	Icc	Minimum cycle				
supply		$V_{1N} = V_{1L}$ or $V_{1H}$ , $I_{1/0} = OmA$ , $\overline{CE} = V_{1L}$		25	_4 5	mA
current	Iccı	the, the =1 $\mu$ s				
		$V_{1N} = V_{1L}$ or $V_{11}$ , $I_{1/0} = OmA$ , $\overline{CE} = V_{1L}$			10	mA
Standby	Іѕв	$\overline{CE} \geq V_{cc} - 0.2V$		0.6	40	μΑ
current	Isвi	CE =V1H			3	mA
Output	Vol	Iol= 2.1mA ·		4	0.4	V
voltage	Vон	Ion=-1. OmA	2.4			V

Note) \*4. Typical values at Vcc=5.0V, Ta=25°C.

### 8. AC Electrical Characteristics

AC Test Conditions

Input pulse level	0.6V to 2.4V
Input rise and fall time	1 0 n s
Input and Output timing Ref. level	1.5 V
Output load	$1TTL+C_{L}(100pF)(*5)$

Note) **\***5. Including scope and jig capacitance.

### Read cycle

$(T_a = 0 C)$	to +70℃	,Vcc=	4.5 V to	5.5V	)
Parameter	Symbol	Min.	Max.	Unit	
Read cycle time	trc	70		ns	1
Address access time	t AA		70	ns	
CE access time	t ACE		70	ns	]
Output enable to output valid	toe		3 5	ns	
Output hold from address change	tон	10		ńs	]
CE Low to output active	tız	10		ns	* 6
OE Low to output active	tolz	5		ns	* 6
CE High to output in High impedance	tнz	0	3 0	ns	* 6
OE High to output in High impedance	tонz	0	3 0	ns	* 6

#### Write cycle

 $(T_a = 0 \ C \ to + 7 \ 0 \ C \ , Vcc = 4.5 \ V \ to 5.5 \ V)$ 

Parameter	Symbol	Min.	Max.	Unit	
Write cycle time	twc	70		ns	
CE Low to end of write	tcw	4 5		ns	
Address valid to end of write	t aw	4 5		ns	
Address setup time	tas	0		ns	] -
Write pluse width	twp	35		ns	
Write recovery time	twr	0		ns	
Input data setup time	tow	30		ns	]
Input data hold time	tон	0		ns	
WE High to output active	tow	5		ns	*
WE Low to output in High impedance	twz	0	30	ns	x
OE High to output in High impedance	tонz	0	30	ns	*

Note) \*6. Active output to High impedance and High impedance to output active tests specified for a  $\pm 200$  mV transition from steady state levels into the test load.

SHARP

#### LH525C7D

9. Data Retention Characteristics

				(Ta=	0°C to	+70°	)
Paramenter	Symbol	Conditions		Min.	Typ. (*7)	Max.	Unit
Data Retention	VCCDR	$\overline{CE} \ge V_{CCDR} - 0.2V$					
supply voltage		* •		2.0		5.5	V
Data Retention	ICCDR	$V_{CCDR} = 3 V$	T a = 2 5 °C		0.3	1.0	μΑ
supply current			T a = 4 0 ℃			3.0	μΑ
		$\overline{CE} \ge V CCDR - 0.2 V$	1			15	μΑ
Chip enable	t CDR						
setup time				0			n s
Chip enable	tr			(*8)		÷.	
hold time				trc			ns

Note) **\***7. Typical values at Ta=25°C

\*8. Read Cycle

#### 10. Pin Capacitance

### (Ta = 25°C, f = 1 M H z)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	]
Input capacitance	CIN	$V_{I N} = 0 V$			7	pF	* 9
I/O capacitance	C 1 /0	$V_{1/0} = 0 V$	1		10	рF	*9

Note) \*9. This parameter is sampled and not production tested.

#### LH525C7D



SHARP

#### LH525C7D



SHARP

#### LH525C7D





5. Surface Mount Conditions

Please perform the following conditions when mounting ICs not to deteriorate IC quality.

5-1 .Soldering conditions (The following conditions are valid only for one time soldering.)

Mounting Method	Temperature and Duration	Measurement Point
Solder dipping	245℃ or less, duration of less than 3 seconds/dip, total of 5 seconds. (Only the appropriate parts of leads for soldering are immersed in the surface of a jet stream solder bath. During soldering, the solder stream must not come into direct contact with the plastic body of	Solder bath.
	package.)	n an
Manual soldering (soldering iron)	260°C or less, duration of less than 10 seconds. (Only the appropriate parts of leads for soldering are soldered with a soldering iron. During soldering, the soldering iron must not come into direct contact with the plastic body of package.)	IC outer lead surface.





Static, SRAM, RAM, Random Access Memory, LH52256CD-70LL